



DMP3037LSS

Product Summary

BV _{DSS}	Rds(on) max	ID TA = +25°C	
-30V	32mΩ @ V _{GS} = -10V	-5.8A	
	50mΩ @ V _{GS} = -4.5V	-4.6A	

Description

This new generation MOSFET has been designed to minimize the onstate resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- DC-DC converters
- Power management functions
- Backlighting

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

P-CHANNEL ENHANCEMENT MODE MOSFET

https://www.diodes.com/products/automotive/automotiveproducts/.

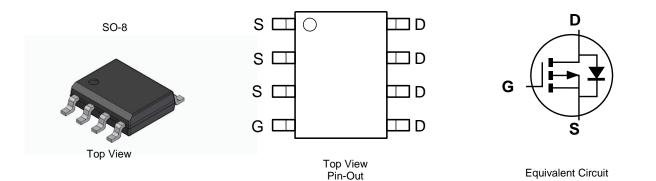
This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/guality/product-definitions/

 An Automotive-Compliant Part is Available Under Separate Datasheet (<u>DMP3037LSSQ</u>)

Mechanical Data

- Package: SO-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Plated over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram Below
- Weight: 0.072 grams (Approximate)



Ordering Information (Note 4)

Part Number	Package	Packing		
Part Number		Qty.	Carrier	
DMP3037LSS-13	SO-8	2500	Tape & Reel	

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

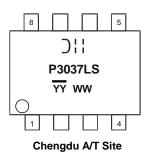
Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

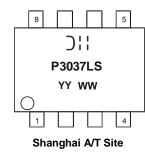
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Notes:



Marking Information





);; = Manufacturer's Marking P3037LS = Product Type Marking Code YYWW = Date Code Marking YY or YY = Year (ex: 22 = 2022) WW = Week (01 to 53) <u>YY</u> = Date Code Marking for SAT (Shanghai Assembly/ Test Site) <u>YY</u> = Date Code Marking for CAT (Chengdu Assembly/ Test Site)

Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		Vdss	-30	V
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current (Note 6) V _{GS} = -10V	T _A = +25°C T _A = +70°C	ID	-5.8 -4.6	А
Pulsed Drain Current (10µs Pulse, Duty cycle = 1%)		Ідм	-40	А
Avalanche Current (Note 7) L = 0.1mH		las	-17	А
Avalanche Energy (Note 7) L = 0.1mH		Eas	15	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	D -	1.2	W
Total Power Dissipation (Note 5)	T _A = +70°C	PD	0.8	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	100	°C/W
	t < 10s	Reja	58	
Total Power Dissipation (Note 6)	T _A = +25°C	D-	1.6	W
	$T_A = +70^{\circ}C$	PD	1.0	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	77	°C/W
	t < 10s	Reja	45	
Thermal Resistance, Junction to Case (Note 6)		R _{0JC}	10	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

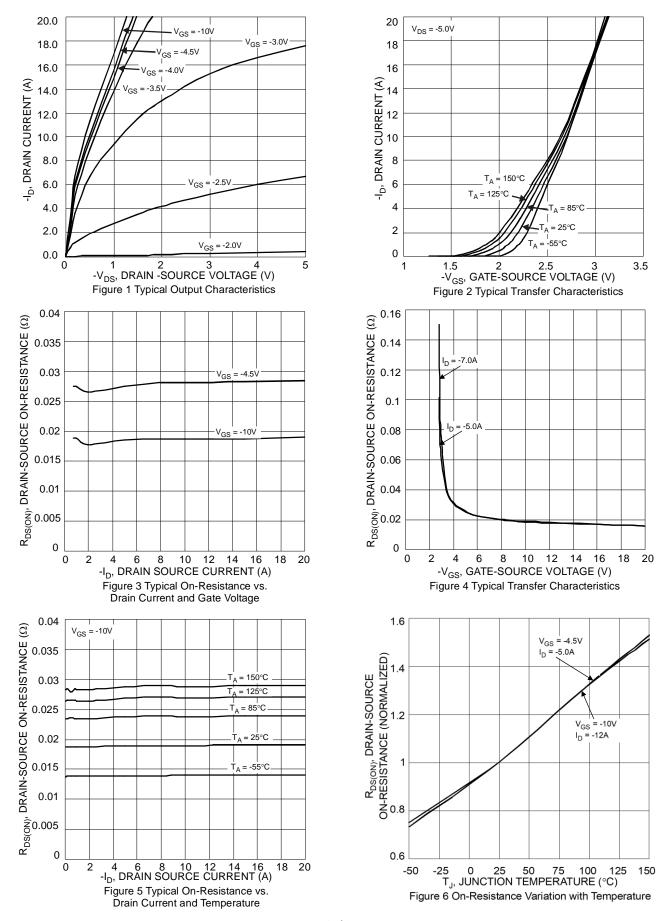


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

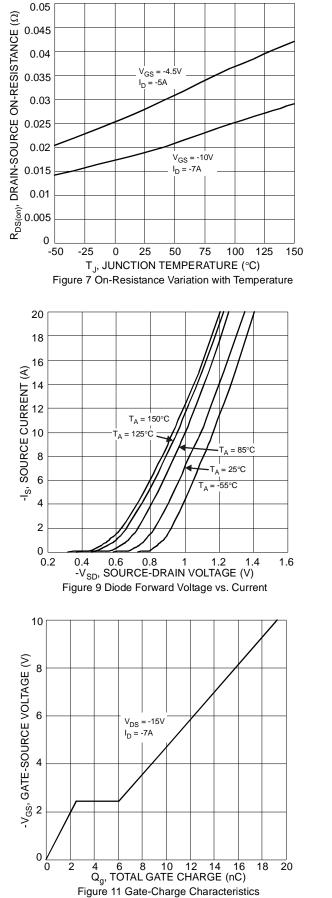
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	-30		—	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current TJ = +25°C	IDSS	—	—	-1.0	μA	$V_{DS} = -30V$, $V_{GS} = 0V$
Gate-Source Leakage	Igss	—	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	Vgs(th)	-1.0	—	-2.4	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$
Static Drain-Source On-Resistance	Basian		19	32	mΩ	$V_{GS} = -10V, I_D = -7A$
	Rds(on)	_	28	50	11122	$V_{GS} = -4.5V, I_{D} = -5A$
Diode Forward Voltage	V _{SD}	—	-0.75	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss	—	931		pF	
Output Capacitance	Coss	—	120		pF	Vps = -15V, Vgs = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	—	102	—	pF	
Gate Resistance	Rg	-	23	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = -10V)	Qg	—	19.3	_	nC	V _{DS} = -15V, I _D = -7A
Total Gate Charge (V _{GS} = -4.5V)	Qg	—	9.7	—	nC	
Gate-Source Charge	Qgs	—	2.5	_	nC	V _{DS} = -15V, I _D = -7A
Gate-Drain Charge	Q _{gd}	—	3.6	—	nC	
Turn-On Delay Time	t _{D(ON)}	—	3.2	—	ns	
Turn-On Rise Time	tR	—	11.5	_	ns	V _{DS} = -15V, V _{GS} = -10V,
Turn-Off Delay Time	tD(OFF)	—	55.8	_	ns	$R_L = 2.15\Omega$, $R_{GEN} = 3\Omega$
Turn-Off Fall Time	tF	_	30.8		ns	
Body Diode Reverse Recovery Time	trr	_	13.6	—	ns	Is = -7A, dl/dt = 100A/µs
Body Diode Reverse Recovery Charge	QRR	—	3.4	_	nC	Is = -7A, dI/dt = 100A/µs

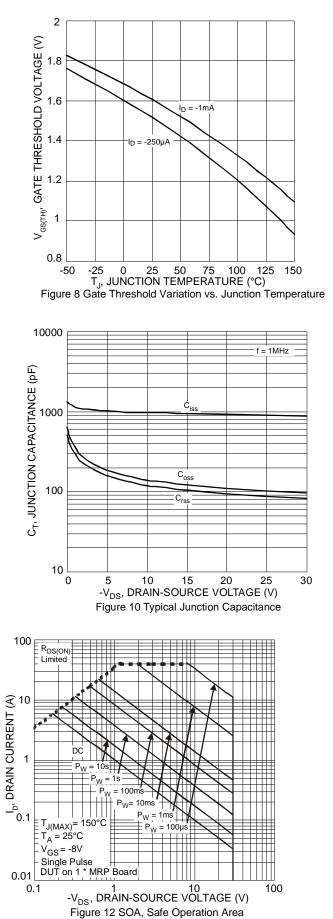
Notes:8. Short duration pulse test used to minimize self-heating effect.9. Guaranteed by design. Not subject to product testing.





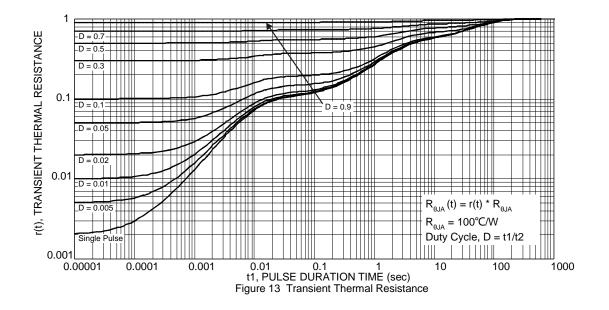






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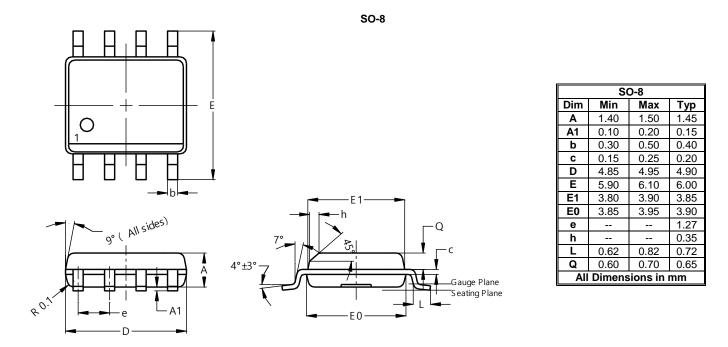






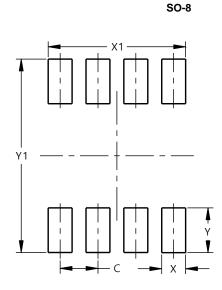
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50



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